## NSN 5961-01-323-0499

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-323-0499 **Inclosure Material:** Glass **Overall Length:** 0.160 inches **Terminal Length:** 0.800 inches **End Application:** Lgm30g **Mounting Method:** Terminal **Terminal Circle Diameter:** 0.030 inches **Criticality Code Justification:** Agav **Semiconductor Material:** Silicon **Voltage Rating In Volts Per Characteristic:** 6.8 regulator voltage **Power Rating Per Characteristic:** 1.5 watts any acceptable preset **Maximum Operating Tempurature Per Measurement Point:** 160.0 degrees celsius junction **Special Features:** Part of network, pulse; used on missile guidance set **Nuclear Hardness Critical Feature:** Hardened **Terminal Type And Quantity:** 2 pin Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig:

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